

SPP11N65C3

Data Sheet

N-Channel MOSFETs (>500V...900V); Package: PG-TO220-3; VDS (max): 650.0 V; Package: TO-220; RDS(ON) @ TJ=25°C VGS=10: 380.0 mOhm; ID(max) @ TC=25°C: 11.0 A; IDpuls (max): 33.0 A;,MOSFET COOL MOS N-CH 650V 11A

Manufacturers

Infineon Technologies Corporation

Package/Case

TO-220

Product Type

Transistors

RoHS

Rohs



Images are for reference only

Please submit RFQ for SPP11N65C3 or Email to us: sales@ovaga.com We will contact you in 12 hours.

RFO

General Description

Lifecycle

650V CoolMOSTM C3 is Infineon's third series of CoolMOSTM with market entry in 2001. **Replacement for 650V CoolMOSTM C3 is CoolMOSTM P7.**

Low specific on-state resistance (R_{DS(on)}*A)

Very low energy storage in output capacitance (E_{oss}) @400V

Low gate charge (Q_g)

Fieldproven CoolMOSTM quality

CoolMOSTM technology has been manufactured by Infineon since 1998

High efficiency and power density

Outstanding cost/performance

High reliability

Ease-of-use

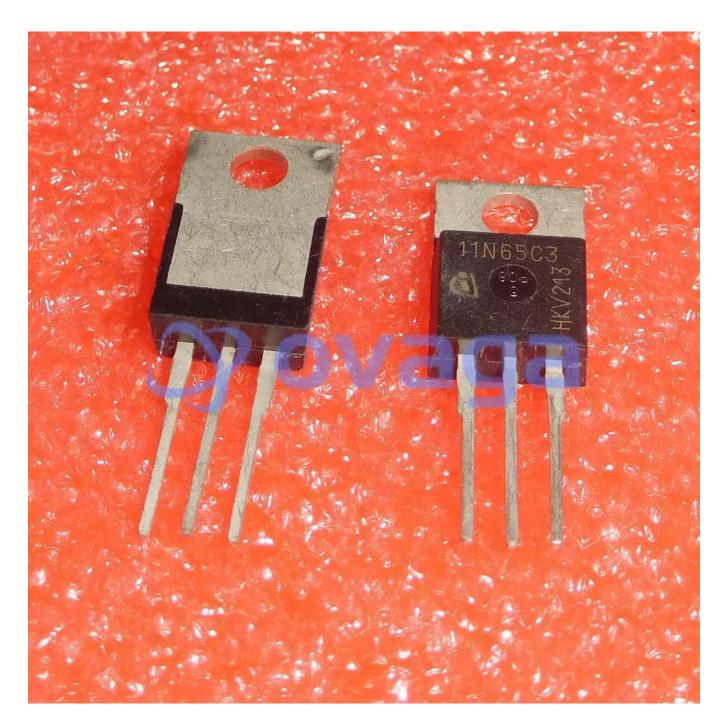
Consumer

PC power

Adapter

Features	Application
Low specific on-state resistance (R	Consumer
DS(on)	PC power
Very low energy storage in output capacitance (E	Adapter
oss	
Low gate charge (Q	
g	
Fieldproven CoolMOS TM quality	
CoolMOS TM technology has been manufactured by Infineon since 1998	
High efficiency and power density	
Outstanding cost/performance	
High reliability	
Ease-of-use	





Related Products



BSP613P

Infineon Technologies Corporation SOT-223



SPP07N60S5

Infineon Technologies Corporation P-TO220-3-1



SPP07N65C3

Infineon Technologies Corporation TO-220AB



SPP11N60C3XKSA1

Infineon Technologies Corporation PG-TO220



IRF640NSPBF
Infineon Technologies Corporation
PAK-3

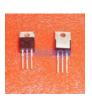


Infineon Technologies Corporation TO-252

SPD03N60S5



SPP20N60CFD
Infineon Technologies Corporation
TO-220AB



SPP07N60C3
Infineon Technologies Corporation
TO-220AB